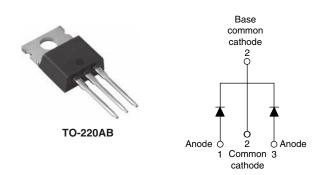
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 30 A



www.vishay.com

PRODUCT SUMMARY								
Package	TO-220AB							
I _{F(AV)}	2 x 30 A							
V _R	150 V							
V_F at I_F	0.72 V							
I _{RM} max.	20 mA at 125 °C							
T _J max.	175 °C							
Diode variation	Common cathode							
E _{AS}	0.4 mJ							

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



COMPLIANT

HALOGEN

FREE

- Guard-ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	60	А						
V _{RRM}		150	V						
I _{FSM}	t _p = 5 μs sine	710	А						
V _F	30 A_{pk} , T_J = 125 °C (typical, per leg)	0.69	V						
TJ	Range	-55 to +175	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-60CTQ150HN3	UNITS					
Maximum DC reverse voltage	V _R	150	N/					
Maximum working peak reverse voltage	V _{RWM}	150	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
Maximum average forward per leg		E0.0 duty avala at T = 127.0		30					
current, see fig. 5 per device	I _{F(AV)}	50 % duty cycle at T_C = 137 °C, rectangular waveform		60	•				
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	710	A				
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	270					
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.9 A, L = 1 mH		0.4	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.9	А				

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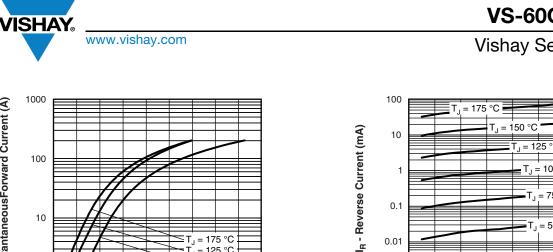
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ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS							
Maximum forward voltage drop per leg See fig. 1		30 A	T.I = 25 °C	0.83	0.88					
	V _{FM} ⁽¹⁾	60 A	1j=25 0	0.98	1.09	V				
	VFM V	30 A	T.I = 125 °C	0.67	0.72					
		60 A	1j=125 0	0.82	0.87					
Maximum reverse leakage current per leg	I _{RM}	T _J = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	7	75	μA				
See fig. 2		T _J = 125 °C	VR - naleu VR	7.2	20	mA				
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25		-	650	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	-	7.5	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	PARAMETER		TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to +175	°C				
Maximum thermal resistance,	per leg	P	DC operation, see fig. 4	1.2					
junction to case per pack		R _{thJC}	DC operation	0.6	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased 0						
Approximate weight				6	g				
Approximate weight				0.21	oz.				
Mounting torgue	minimum			6 (5)	kgf ⋅ cm				
	maximum			12 (10)	$(lbf \cdot in)$				
Marking device			Case style TO-220AB	60CTC	Q150H				



VS-60CTQ150HN3

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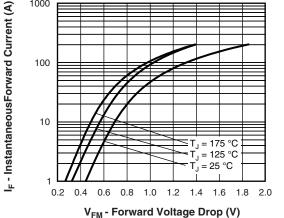


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

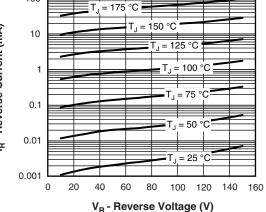


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

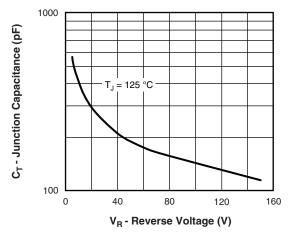


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

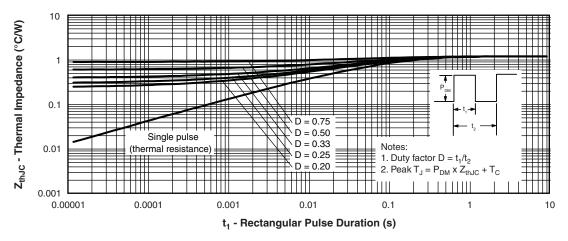
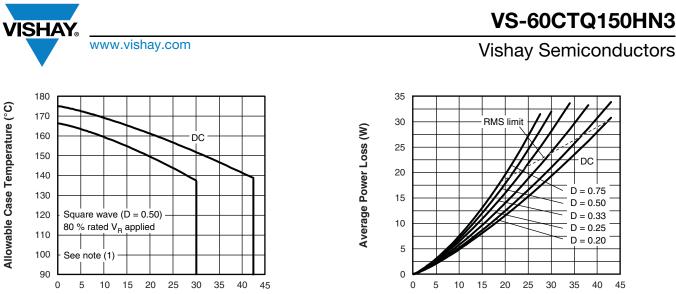
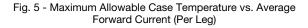


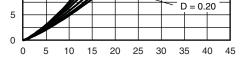
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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I_{F(AV)} - Average Forward Current (A)

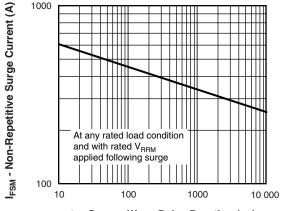




DC

I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)



tp - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

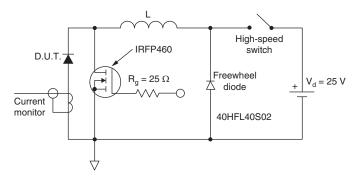


Fig. 8 - Unclamped Inductive Test Circuit

Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; (1)

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 09-Jan-15

4

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ORDERING INFORMATION TABLE

Device code	VS-	60	с	т	Q	150	Н	N3
		2	3	4	5	6	7	8
1 2 3	-	Curren		onductor (60 = 60	•	ct		
4	-		mmon c					
5	-		ky "Q" se	eries (150 = 1	50 V)			
7	-	H = AE	0	qualifie	,			
				free, Ro	HS-com	ipliant, a	and tota	lly lead

ORDERING INFO	RMATION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-60CTQ150HN3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95222					
Part marking information	www.vishay.com/doc?95028					

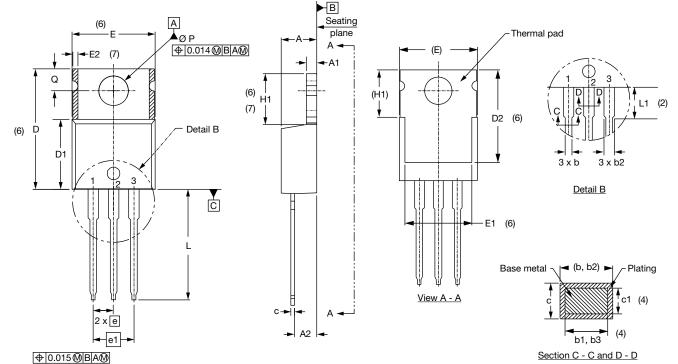
Outline Dimensions



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC[®] outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC[®] TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

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